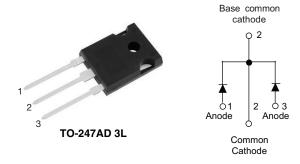


650 V Power SiC Gen 3 Merged PIN Schottky Diode, 2 x 10 A



LINKS TO ADDITIONAL RESOURCES





PRIMARY CHARACTERISTICS						
I _F	2 x 10 A					
V _R	650 V					
V _F at I _F at 25 °C, typ.	1.3 V					
T _J max.	175 °C					
I _R at V _R at 175 °C	4.5 μA					
Q _C (V _R = 400 V)	29 nC					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

FEATURES

· Majority carrier diode using Schottky technology on SiC wide band gap material



 Improved V_F and efficiency by thin wafer RoHS technology

COMPLIANT HALOGEN **FREE**

 Positive V_F temperature coefficient, for easy paralleling

- Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- · MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Solder Bath temperature 275 °C maximum, 10 s per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

MECHANICAL DATA

Case: TO-247AD 3L

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102 Mounting torque: 10 in-lbs maximum

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V_{RRM}		650	V	
Continuous forward surrent per les	$I_F^{(1)}$ $T_C = 146 ^{\circ}C (DC)$		10	Α	
Continuous forward current, per leg	I _F ⁽²⁾	$T_C = 154 ^{\circ}C (DC)$	10	A	
DC blocking voltage	V_{DC}		650	V	
Repetitive peak forward current	I _{FRM}	$T_C = 25$ °C, f = 50 Hz, square wave, DC = 25 %	41		
No. 1982 and Company of the control of the	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	60	Α	
Non-repetitive peak forward surge current, per leg		$T_C = 110$ °C, $t_p = 10$ ms, half sine wave	58		
	P _{tot} ⁽¹⁾	T _C = 25°C	79	W	
Dower discipation, you los		T _C = 110 °C	34	VV	
Power dissipation, per leg	P _{tot} (2)	T _C = 25°C	107	w	
		T _C = 110 °C	46	VV	
124	6.2	T _C = 25°C	18	A ² s	
I ² t value, per leg	∫i ² dt	T _C = 110 °C	17	ALS	
Operating junction and storage temperatures	TJ ⁽²⁾ , T _{Stq}		-55 to +175	°C	

Notes

- (1) Based on maximum Rth
- (2) Based on typical Rth
- (3) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_{cl} < 1/R_{B,IA}$



ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
		I _F = 10 A	-	1.3	1.5		
Forward voltage, per leg	V _F	I _F = 10 A, T _J = 150 °C	-	1.46	1.85	V	
		I _F = 10 A, T _J = 175 °C	-	1.52	-		
	I _R	$V_R = V_R$ rated	-	0.7	55	μΑ	
Reverse leakage current, per leg		V _R = V _R rated, T _J = 150 °C	-	2.8	125		
		V _R = V _R rated, T _J = 175 °C	-	4.5	-		
Total capacitance, per leg	С	V _R = 1 V, f = 1 MHz	-	445	-		
Total capacitatice, per leg		V _R = 400 V, f = 1 MHz	-	43	-	pF	
Total capacitive charge, per leg	Q _C	V _R = 400 V, f = 1 MHz	-	29	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS (T _A = 25 °C unless otherwise specified)							
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS							UNITS
Thermal resistance, junction-to-case	per leg	— R _{th IC}		-	1.4	1.9	°C/W
	per device			-	0.8	1	°C/W
Marking device			3C20CP07L				

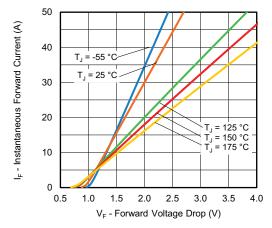


Fig. 1 - Typical Forward Voltage Drop Characteristics, Per Leg

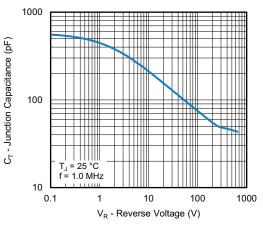


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg

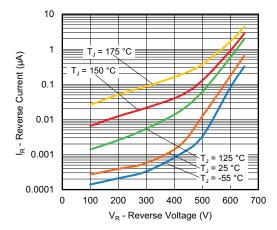


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg

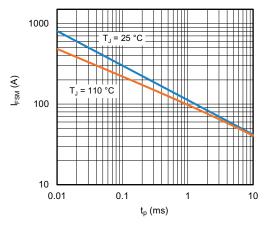


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration, Per Leg (Square Wave)



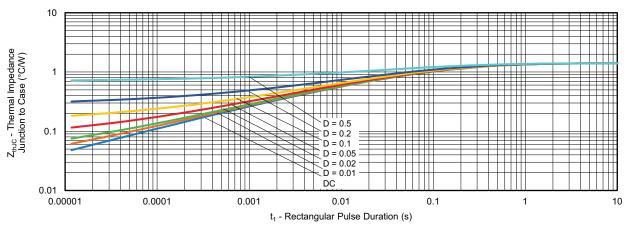


Fig. 5 - Typical Thermal Impedance Z_{thJC} Characteristics, Per Leg

10

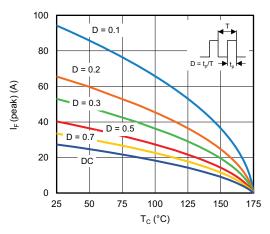


Fig. 6 - Peak Forward Current vs. Maximum Allowable Case Temperature, Per Leg

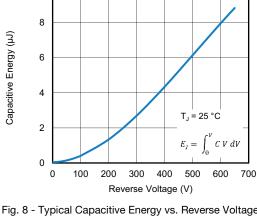


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage, Per Leg

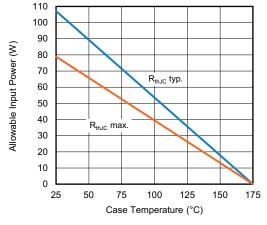


Fig. 7 - Forward Power Loss Characteristics, Per Leg

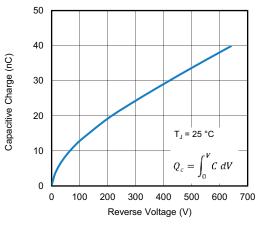
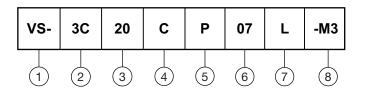


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage, Per Leg



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- 3C = SiC diode, Generation 3

Current rating (20 = 20 A)

- C = common cathode

P = package TO-247

Voltage rating: (07 = 650 V)

7 - L = long lead

Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

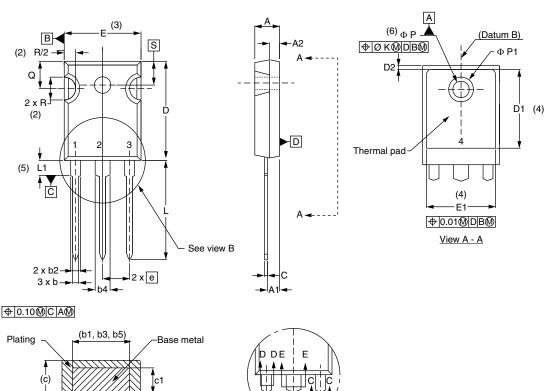
ORDERING INFORMATION					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-3C20CP07L-M3	25/tube	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95626
Part marking information	www.vishay.com/doc?95007



TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

	MILLIMETERS INCHES				
SYMBOL	IVIILLIIV	IETEKS	INC	NOTES	
01111202	MIN.	MAX.	MIN.	MAX.	
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

Section C - C, D - D, E - E

SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215	BSC	
ØΚ	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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